

12 x 12 PARALLEL CMOS MULTIPLIER-ACCUMULATOR

IDT7209L

FEATURES:

- 12 x 12 parallel multiplier/accumulator with selectable accumulation and subtraction
- High-speed 30ns maximum multiply/accumulate time
- Selectable accumulation, subtraction, rounding and preloading with 27-bit result
- Pin and functionally compatible with the TRW TDC1009J
- Performs subtraction and double precision addition and multiplication
- Produced using advanced CEMOS[™] high-performance technology
- Low-power consumption (less than 150mW typical) less than 1/10 the power of compatible bipolar
- · Inputs and outputs directly TTL-compatible
- Single 5V supply
- Available in DIP, SHRINK-DIP, plastic DIP or LCC
- Military product available 100% screened to MIL-STD-883, Class B



DESCRIPTION:

The IDT7209 is a high-speed, low-power 12 x 12 parallel multiplier/accumulator that is ideally suited for real-time digital signal processing applications. Fabricated using IDT's CEMOS silicon gate technology, this device offers a very low-power alternative to existing bipolar and NMOS counterparts, with only 1/10 the power dissipation and exceptional speed (30ns maximum) performance.

A pin and functional replacement for TRW's TDC1009J, the IDT7209 operates from a single 5 volt supply and is compatible with standard TTL logic levels. The architecture of the IDT7209 is fairly straightforward, featuring individual input and output registers with clocked D-type flip-flops, a preload capability which enables input data to be preloaded into the output registers, individual three-state output ports for the extended product (XTP) and most significant product (MSP), and a least significant product (LSP) output.

The X_{IN} and Y_{IN} data input registers may be specified through the use of the two's complement input (TC) as either two's complement or an unsigned magnitude, yielding a full-precision 24-bit result that may be accumulated to a full 27-bit result. The three output registers—extended product (XTP), most significant product (MSP) and least significant product (LSP)—are controlled by the respective TSX, TSM and TSL input lines.

The accumulate input (ACC) enables the device to perform either a multiply or a multiply-accumulate function. In the multiply-accumulate mode, output data can be added to or subtracted from subsequent results. When the subtraction (SUB) input is active simultaneously with an active ACC, a subtraction can be performed. The double precision accumulated result is rounded down to either a single precision or single precision plus 3-bit extended result. In the multiply mode, the extended product output (XTP) is sign extended in the two's complement mode or set to zero in the unsigned mode. The ROUND (RND) control rounds up the most significant product (MSP) and the 3-bit extended product (XTP) outputs. When preload input (PREL) is active, all the output buffers are forced into a high-impedance state (see PRELOAD truth table) and external data can be loaded into the output register by using the TSX, TSL and TSM signals as input controls.

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MILITARY AND COMMERCIAL TEMPERATURE RANGES

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PIN CONFIGURATIONS





ABSOLUTE MAXIMUM RATING⁽¹⁾

| SYMBOL | RATING | COMMERCIAL | MILITARY | UNIT |
|-------------------|--|--------------|--------------|------|
| V _{TERM} | Terminal Voltage with Respect to GND | -0.5 to +7.0 | -0.5 to +7.0 | v |
| T _A | Operating Temperature | 0 to +70 | -55 to +125 | °C |
| T _{BIAS} | Temperature Under Bias | -55 to +125 | ~65 to +135 | °C |
| T _{STG} | Storage Temperature | -55 to +125 | -65 to +150 | °C |
| PT | Power Dissipation | 1.6 | 1.6 | w |
| IOUT | DC Output Current | 50 | 50 | mA |

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC ELECTRICAL CHARACTERISTICS

(Commercial V_{CC} = 5V \pm 10%, T_A = 0°C to +70°C, Military V_{CC} = 5V \pm 10%, T_A = -55°C to +125°C) for Commercial clocked multiply times of 30,45,55,65ns or Military, 40,55,65,75ns

| SYMBOL | PARAMETER | TEST CONDITIONS | | MMERC TYP. ⁽¹⁾ | MAX. | MIN. | MILITAR TYP. ⁽¹⁾ | Y MAX. | UNIT |
|-------------------------------------|---|---|-----|------------------------------|------|------|--------------------------------|-----------|------------|
| I _{LI} | Input Leakage Current | V_{CC} = Max., V_{IN} = 0 to V_{CC} | - | | 10 | | | 20 | μA |
| I _{LO} | Output Leakage Current | Hi Z, V _{CC} = Max., V _{OUT} = 0 to V _{CC} | _ | - | 10 | - | | 20 | μA |
| I _{CC} ⁽²⁾ | Operating Power Supply Current | Outputs Open Measured at 10MHz ⁽²⁾ | _ | 40 | 80 | - | 40 | 100 | mA |
| I _{CCQ1} | Quiescent Power Supply Current | $V_{IN} \ge V_{IH}, V_{IN} \le V_{IL}$ | | 20 | 50 | | 20 | 50 | mA |
| I _{CCQ2} | Quiescent Power Supply Current | $V_{\text{IN}} \geq V_{\text{CC}}$ – 0.2V, $V_{\text{IN}} \leq 0.2V$ | | 4 | 20 | | 4 | 25 | mA |
| I _{CC} /f ^(2,3) | Increase in Power Supply Current/MHz | V _{CC} = Max., f > 10MHz | _ | _ | 6 | | | 8 | mA/ MHz |
| V _{OH} | Output High Voltage | V _{CC} = Min., I _{OH} = -2.0mA | 2.4 | _ | _ | 2.4 | | | v |
| V _{OL} | Output Low Voltage | V _{CC} = Min., I _{OL} = 8mA | _ | | 0.4 | _ | | 0.4 | V |

NOTES:

1. Typical implies V_{CC} = 5V and T_A = +25°C.

I_{CC} is measured at 10MHz and V_{IN} = TTL voltages. For frequencies greater than 10MHz, the following equation is used for the commercial range: I_{CC} = 80 + 6(f - 10) mA, where f = operating frequency in MHz. For the military range, I_{CC} = 100 + 8(f - 10) where f = operating frequency in MHz.

3. For frequencies greater than 10MHz.

DC ELECTRICAL CHARACTERISTICS

(Commercial V_{CC} = 5V \pm 10%, T_A = 0°C to +70°C, Military V_{CC} = 5V \pm 10%, T_A = -55°C to +125°C) for Commercial clocked multiply times of 100,135ns or Military, 120,170ns

| SYMBOL | PARAMETER | TEST CONDITIONS | | MMERC TYP.(1) | MAX. | MIN. | MILITAR TYP. ⁽¹⁾ | Y MAX. | UNIT |
|-------------------------------------|---|---|-----|------------------|------|------|--------------------------------|-----------|------------|
| (i _{ti}) | Input Leakage Current | V_{CC} = Max., V_{IN} = 0 to V_{CC} | - | - | 2 | | | 10 | μA |
| I _{LO} | Output Leakage Current | Hi Z, V _{CC} = Max., V _{OUT} = 0 to V _{CC} | - | | 2 | | _ | 10 | μA |
| I _{CC} ⁽²⁾ | Operating Power Supply Current | Outputs Open Measured at 10MHz ⁽²⁾ | | 30 | 60 | | 30 | 80 | mA |
| I _{CCQ1} | Quiescent Power Supply Current | $V_{IN} \ge V_{IH}, V_{IN} \le V_{IL}$ | - | 10 | 30 | | 10 | 30 | mA |
| I _{CCQ2} | Quiescent Power Supply Current | $V_{IN} \ge V_{CC}$ – 0.2V, $V_{IN} \le 0.2V$ | - | 0.1 | 1.0 | | 0.1 | 2.0 | mA |
| I _{CC} /f ^(2,3) | Increase in Power Supply Current/MHz | V _{CC} = Max., f > 10MHz | - | | 5 | | | 7 | mA/ MHz |
| V _{OH} | Output High Voltage | V _{CC} = Min., I _{OH} = -2.0mA | 2.4 | | | 2.4 | | | V |
| V _{OL} | Output Low Voltage | V _{CC} = Min., I _{OL} = 8mA | - | _ | 0.4 | - | | 0.4 | V |

NOTES:

1. Typical implies V_{CC} = 5V and T_A = +25°C.

I_{CC} is measured at 10MHz and V_{IN} = TTL voltages. For frequencies greater than 10MHz, the following equation is used for the commercial range: I_{CC} = 60 + 5(f - 10) mA, where f = operating frequency in MHz. For the military range, I_{CC} = 80 + 7(f - 10) where f = operating frequency in MHz.

3. For frequencies greater than 10MHz.

RECOMMENDED DC OPERATING CONDITIONS

| SYMBOL | PARAMETER | MIN. | TYP. | MAX. | UNIT |
|------------------|---------------------------|------|------|------|------|
| V _{CCM} | Military Supply Voltage | 4.5 | 5.0 | 5.5 | V |
| V _{cc} | Commercial Supply Voltage | 4.5 | 5.0 | 5.5 | V |
| GND | Supply Voltage | 0 | 0 | 0 | V |
| VIH | Input High Voltage | 2.0 | | | V |
| V _{IL} | Input Low Voltage | — | | 0.8 | V |

AC TEST CONDITIONS

| Input Pulse Levels | GND to 3.0V |
|-------------------------------|---------------------|
| Input Rise/Fall Times | 5ns |
| Input Timing Reference Levels | 1.5V |
| Output Reference Levels | 1.5V |
| Output Load | See Figures 1 and 2 |

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

| SYMBOL | PARAMETER ⁽¹⁾ | CONDITIONS | TYP. | UNIT |
|------------------|--------------------------|-----------------------|------|------|
| CIN | Input Capacitance | V _{IN} = 0V | 10 | pF |
| C _{OUT} | Output Capacitance | V _{OUT} = 0V | 12 | pF |

NOTE:

1. This parameter is sampled and not 100% tested.



Figure 1. AC Output Test Load

Figure 2. Output Three State Delay Load (V_x = 0V or 2.6V)

TEST SYMBOL PARAMETER IDT7209L-30 IDT7209L-45 IDT7209L-65 IDT7209L-100 IDT7209L-135 UNITS LOAD MIN. MAX. MIN. MIN. MAX. MIN. MAX. MIN. FIG. MAX. MAX. Multiply-Accumulate Time 30 65 100 135 45 1 t_{MA} _ _ ----------ns Output Delay 25 25 35 35 40 ns 1 t_D -_ ----t_{ENA} 3-State Output Enable Delay(1) _ 25 -----25 -----30 -----35 -----40 ns 2 t_{DIS} 3-State Output Disable Delay(1) 25 25 30 35 40 ns 2 Input Register Setup Time 25 12 15 25 25 ts _ _ ----_ ____ ns -----Input Register Hold Time 3 3 3 0 0 t_H ____ ____ _ -----ns -Clock Pulse Width 10 15 25 _ 25 25 ns ------t_{PW} ____

AC ELECTRICAL CHARACTERISTICS COMMERCIAL (V_{CC} = 5V ± 10%, T_A = 0°C to +70°C)

AC ELECTRICAL CHARACTERISTICS MILITARY ($V_{CC} = 5V \pm 10\%$, $T_A = 0^{\circ}C$ to +125°C)

| SYMBOL | PARAMETER | IDT72 MIN. | 09L-40 MAX. | IDT72 MIN. | 09L-55 MAX. | IDT72 MIN. | 209L-75 MAX. | IDT720 MIN. | 09L-120 MAX. | IDT 72 MIN. | 09L-170 MAX. | UNITS | TEST LOAD FIG. |
|------------------|--|---------------|----------------|---------------|----------------|---------------|-----------------|----------------|-----------------|----------------|-----------------|-------|----------------------|
| t _{MA} | Multiply-Accumulate Time | | 40 | - | 55 | - | 75 | _ | 120 | | 170 | ns | 1 |
| t _D | Output Delay | | 25 | - | 30 | - | 35 | | 40 | | 45 | ns | 1 |
| t _{ENA} | 3-State Output Enable Delay ⁽¹⁾ | - | 25 | - | 30 | - | 35 | - | 40 | - | 45 | ns | 2 |
| t _{DIS} | 3-State Output Disable Delay(1) | - | 25 | - | 30 | - | 35 | - | 40 | - | 45 | ns | 2 |
| t _S | Input Register Setup Time | 15 | | 20 | | 25 | | 30 | | 30 | | ns | - |
| t _H | Input Register Hold Time | 3 | | 3 | | 3 | | 0 | | 0 | | ns | - |
| t _{PW} | Clock Pulse Width | 15 | | 20 | | 30 | | 30 | | 30 | - | ns | |

NOTE:

1. Transition is measured \pm 500mV from steady state with loading specified in Fig. 2.



Figure 3. Set Up and Hold Time



Figure 4. Three State Control Timing Diagram



Figure 5. Timing Diagram

SIGNAL DESCRIPTIONS:

INPUTS:

X_{IN} (X₁₁-X₀) Multiplicand Data Inputs Y_{IN} (Y₁₁-Y₀) Multiplier Data Inputs

INPUT CLOCKS: CLKX, CLKY

OLINA, OLINI

Input data is loaded on the rising edge of these clocks.

CONTROLS:

ACC (Accumulate)

When ACC is high, the contents of the XTP, MSP and LSP registers are added to or subtracted from the multiplier output. When ACC is low, the device acts as a simple multiplier with no accumulation being performed and the next product generated will be stored directly into the output registers. The ACC signal is loaded on the rising edge of the CLKX or CLKY and must be valid for the duration of the data input.

SUB (Subtract)

When the ACC and SUB signals are both high, the contents of the output register are subtracted from the next product generated and the difference is stored back into the output registers at the rising edge of the next CLKP. When ACC is high and SUB is low, an addition instead of a subtraction is performed. Like the ACC signal, the SUB signal is loaded into the SUB register at the rising edge of either CLKX or CLKY and must be valid over the same period as the input data is valid. When the ACC is low, SUB acts as a "don't care" input.

TC (Two's Complement)

When the TC Control is HIGH, it makes both the X and Y input, two's complement inputs. When the TC Control is LOW, it makes both inputs, X and Y, unsigned magnitude inputs.

RND (Round)

A high level at this input adds a "1" to the most significant bit of the LSP to round up the XTP and MSP data. RND, like ACC and SUB, is loaded on the rising edge of either CLKX or CLKY and must be valid for the duration of the input data.

PREL (Preload)

When the PREL input is high, the output is driven to a high impedance state. When the TSX, TSL and TSM inputs are also high, the contents of the output register can be preset to the preload data applied to the output pins at the rising of CLKP. The PREL, TSM TSL and TSX inputs must all be valid over the same period that the preload input is valid.

TSX, TSL, TSM (Three State Output Controls)

The XTP, MSP and LSP registers are controlled by direct non-registered control signals. These output drivers are at high impedance (disabled) when control signals TSX, TSM and TSL are high and are enabled when TSX, TSM and TSL are low.

OUTPUT CLOCK:

CLKP

Output data is loaded into the output register on the rising edge of this clock.

OUTPUTS:

XTP (P₂₆-P₂₄)

Extended Product Output (3-bits)

MSP (P23-P12)

Most Significant Product

LSP (P11-P0)

Least Significant Product

NOTES ON TWO'S COMPLEMENT FORMATS:

1. In two's complement notation, the location of the binary point that signifies the separation of the fractional and integer fields is just after the sign, between the sign bit (-2°) and the next significant bit for the multiplier inputs. This same format is carried over to the output format, except that the extended significance of the integer field is provided to extend the utility of the accumulator. In the case of the output notation, the output binary point is located between the 2° and 2^{-1} bit positions. The location of the binary point is arbitrary, as long as there is consistency with both the input and output formats. The number field can be considered entirely integer with the binary point just to the right of the least significant bit for the input, product and the accumulated sum.

2. When in the non-accumulating mode, the first four bits (P_{26} through P_{23}) will all indicate the sign of the product. Additionally, the P_{22} term will also indicate the sign except for one exceptional

case when multiplying -1×-1 . With the additional bits that are available in this multiplier, the -1×-1 is valid operation that yields a +1 product.

3. In operations that require the accumulation of single products or sum of products, there is no change in format. To allow for a valid summation beyond that available for a single multiplication product, three additional significant bits (guard bits) are provided. This is the same as if the product was accumulated off-chip in a separate 27-bit wide adder. Taking the sign at the most significant bit position will guarantee that the largest number field will be used. When the accumulated sum only occupies the right hand portion of the accumulator, the sign will be extended into the lesser significant bit positions.

PRELOAD TRUTH TABLE

| PREL | TSX | TSM | TSL | ХТР | MSP | LSP |
|------|-----|-----|-----|------|------|------|
| 0 | 0 | 0 | 0 | Q | Q | Q |
| 0 | 0 | 0 | 1 | Q | Q | Hi Z |
| 0 | 0 | 1 | 0 | Q | Hi Z | Q |
| 0 | 0 | 1 | 1 | Q | Hi Z | Hi Z |
| 0 | 1 | 0 | 0 | Hi Z | Q | Q |
| 0 | 1 | 0 | 1 | Hi Z | Q | Hi Z |
| 0 | 1 | 1 | 0 | Hi Z | Hi Z | Q |
| 0 | 1 | 1 | 1 | Hi Z | Hi Z | Hi Z |
| 1 | 0 | 0 | 0 | Hi Z | Hi Z | Hi Z |
| 1 | 0 | 0 | 1 | Hi Z | Hi Z | PL |
| 1 | 0 | 1 | 0 | Hi Z | PL | Hi Z |
| 1 | 0 | 1 | 1 | Hi Z | PL | PL |
| 1 | 1 | 0 | 0 | PL | Hi Z | Hi Z |
| 1 | 1 | 0 | 1 | PL | Hi Z | PL |
| 1 | 1 | 1 | 0 | PL | PL | Hi Z |
| 1 | 1 | 1 | 1 | PL | PL | PL |

NOTES:

Hi Z = Output buffers at high impedance (output disabled).

Q = Output buffers at low impedance. Contents of output register will be transferred to output pins.

PL = Output buffers at high impedance, or output disabled. Preload data supplied externally at output pins will be loaded into the output register at the rising edge of CLKP.



Figure 6. Fractional Two's Complement Notation

